



PATENT ABSTRACTS OF JAPAN

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(71)Applicant: UCHIHASHI ESTEC CO LTD

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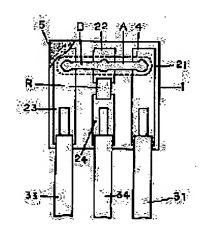
(72)Inventor: UEMURA MITSUAKI

(54) PROTECTIVE ELEMENT AND ITS APPLICATION METHOD

(57)Abstract:

PROBLEM TO BE SOLVED: To provide a highly functional protective element having a simple structure as well as allowing easy manufacture, and a method for using the element, regarding a protective element for fusing a low-fusion point fusible alloy piece via the detection of the overvoltage of equipment, and the subsequent feed of power to a film resistor for heat generation as well as the isolation of the equipment and the film resistor from a power supply.

SOLUTION: The first electrode 21, the second electrode 22, the third electrode 23 and the fourth electrode 24 are arranged on one side of an insulating board 1. In addition, a resistor R is provided across the second electrode 22 and the fourth electrode 24. Also, low-fusion point fusible alloy pieces A and B are respectively laid between the first electrode 21 and the second electrode 22, and between the second electrode 22 and the third electrode 23. Furthermore, flux 4 is applied to the low-fusion point fusible alloy pieces A and B, and one side of the insulating board 1 is covered with an insulation layer 5.



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CLAIMS

[Claim(s)]

[Claim 1] The 1st electrode, the 2nd electrode, the 3rd electrode, and the 4th electrode are prepared on one side of an insulating substrate. Prepare resistance over the 2nd electrode and the 4th electrode, and the pieces A and B of a low-melt point fusible alloy are connected, respectively between the 1st electrode and the 2nd electrode and between the 2nd electrode and the 3rd electrode. The protection component characterized by applying flux to the piece of a low-melt point point fusible alloy, covering one side of the above-mentioned insulating substrate, covering an insulating layer and changing.

[Claim 2] Operation of the protection component characterized by connecting claim 1 thru/or the overvoltage sensing energization circuit which the 1st electrode of the protection component of a publication is connected to a power-source side, the 3rd electrode is connected [circuit] to a protected device side 3 either, respectively, and the overvoltage of a protected device is detected [circuit] between the 1st electrode or the 3rd electrode, and the 4th electrode, and carries out energization generation of heat of the above-mentioned resistance. [Claim 3] It differs in the melting point of the piece A of a low-melt point fusible alloy of a protection component according to claim 1, and the melting point of the piece B of a low-melt point point fusible alloy. Each piece of a low-melt point point fusible alloy is used as a fuse to a different circuit part. Detect a different overvoltage and the overvoltage sensing energization circuit which carries out energization generation of heat of the resistance of a protection component at different temperature is connected. smallness -- energization generation of heat of the resistance is carried out with an overvoltage -- making -- fusing of one piece of a low-melt point fusible alloy -- one circuit part -- from a power source -- intercepting -- after that -- size -- the operation of the protection component characterized by carrying out energization generation of heat of the resistance with an overvoltage, and intercepting the circuit part of another side from a power source by fusing of the piece of a low-melt point point fusible alloy of another side.

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DETAILED DESCRIPTION

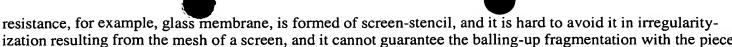
[Detailed Description of the Invention] [0001]

[Field of the Invention] This invention relates to the protection component used in order to protect an electrical machinery and apparatus from an overvoltage, and its operation. [0002]

[Description of the Prior Art] When an overvoltage acts on a device and it intercepts a device from a power

source, as membrane resistance and the piece of a low-melt point fusible alloy are installed on one side of an insulating substrate, the protection component which covers one side of an insulating substrate with an insulating layer, and changes is used and it is shown in drawing 4 This protection component E' and overvoltage sensing energization circuit F', for example, circuit F' which connects zener diode D' and grows into the base side of transistor Tr', are inserted between power-source S' and protected device Z'. If the reverse voltage more than the breakdown voltage of zener diode D' acts on device Z', it is well-known to intercept device Z' from power-source S' by base current flowing, collector current flowing according to this base current, membrane resistance R' generating heat, and piece of low-melt point fusible alloy A' being melted. [0003] However, even if device Z' is intercepted from a power source by fusing of piece of low-melt point point fusible alloy A', when device Z' is a KYAPASHITIBU load (for example, when it is a battery), for residual voltage, base current continues flowing, energization generation of heat of membrane resistance R' may be continued, and it is dangerous with the above-mentioned protection component. [0004] Then, composite electrode 20' which combined central fuse electrode 21' and heater one side T typeface electrode 22' as shown in (b) of drawing 5, As printing formation of side T typeface electrode 23' besides a heater and HI-ZU both-sides electrode 24', and 25' is carried out at substrate 1' and it is shown in (b) of drawing 5 It crosses among T typeface both the arms of heater one side T typeface electrode 22', and side T typeface electrode 23' besides a heater., respectively Membrane resistance R', As prepare R', insulating-layer i' and i' are prepared on each membrane resistance, piece of low-melt point fusible alloy A' and A' are connected between 25', respectively in central fuse electrode 21of composite electrode 20", and fuse both-sides electrode 24' and it is further shown to (Ha) of drawing 5 Using the protection component which covers flux layer 4' and external insulating-layer 5', and changes is proposed (JP,7-153367,A). as the protection network incorporating this protection component showing to drawing 6 -- membrane resistance R' -- it has 2 sets of pairs of piece of low-melt point point fusible alloy A', and that piece of low-melt point fusible alloy A' of a pair of is melted by energization generation of heat of membrane resistance R' of each set. **(ing) -- device Z', if the reverse voltage more than the breakdown voltage of zener diode D' acts on a side Base current flows to transistor Tr' and collector current flows. Both membrane resistance R', Energization generation of heat of R' is carried out, and while each piece of low-melt point point fusible alloy A' and A' are melted by energization generation of heat of each membrane resistance R' and R' and device Z' is intercepted from power-source S', membrane resistance R' and R' are intercepted from power-source S'. [0005]

[Problem(s) to be Solved by the Invention] However, since the pair of the piece of a membrane resistance-low-melt point fusible alloy is 2 sets, the resistance adjustment about two membrane resistance is required of the above-mentioned protection component, manufacture is troublesome, and since it is necessary to prepare superficially 2 sets of pieces of a membrane resistance-low-melt point fusible alloy, it is disadvantageous also for the formation of small size of a protection component. Furthermore, the insulating layer on membrane



ization resulting from the mesh of a screen, and it cannot guarantee the balling-up fragmentation with the piece of a low-melt point point fusible alloy smooth in this basis on it easily.

[0006] The purpose of this invention detects the overvoltage of a device, carries out energization generation of heat of the membrane resistance, and makes the piece of a low-melt point fusible alloy melt, for the

protection component which intercepts a device and membrane resistance from a power source, it is easy

structure and it is to offer the protection component excellent in actuation nature with easy manufacture, and the operation of the protection component.

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[Means for Solving the Problem] The protection component concerning this invention on one side of an insulating substrate The 1st electrode, the 2nd electrode, Prepare the 3rd electrode and the 4th electrode and resistance is prepared over the 2nd electrode and the 4th electrode. It is the configuration which connects the pieces A and B of a low-melt point point fusible alloy, respectively between the 1st electrode and the 2nd electrode and between the 2nd electrode and the 3rd electrode, applies flux to the piece of a low-melt point point fusible alloy, covers one side of the above-mentioned insulating substrate, covers an insulating layer, and changes. The 1st electrode is connected to a power-source side, and it connects the 3rd electrode to a protected device side, respectively, and the protection component concerning this invention detects the overvoltage of a protected device between the 1st electrode or the 3rd electrode, and the 4th electrode, and can connect and use for it the overvoltage sensing energization circuit which carries out energization generation of heat of the above-mentioned resistance.

[0008] Moreover, the protection component concerning this invention differs in the melting point of the piece A of a low-melt point fusible alloy, and the melting point of the piece B of a low-melt point point fusible alloy. Each piece of a low-melt point point fusible alloy is used as a fuse to a different circuit part. Detect a different overvoltage and the overvoltage sensing energization circuit which carries out energization generation of heat of the resistance of a protection component at different temperature is connected. smallness -- energization generation of heat of the resistance is carried out with an overvoltage -- making -- fusing of one piece of a low-melt point point fusible alloy -- one circuit part -- from a power source -- intercepting -- after that -- size -- it can be used also by carrying out energization generation of heat of the resistance with an overvoltage, and intercepting the circuit part of another side from a power source by fusing of the piece of a low-melt point fusible alloy of another side.

[0009]

[Embodiment of the Invention] Hereafter, the gestalt of operation of this invention is explained, referring to a drawing. Drawing 1 shows an example of the protection component concerning this invention. 1 is in drawing 1, heat-resistant insulating substrate, for example, ceramic plate. On one side of an insulating substrate, 21-24 are the 1st electrode of the shape of film which carried out printing formation - the 4th electrode, form the 2nd electrode 22 between the point of the 1st electrode 21, and the point of the 3rd electrode 23, and have separated and prepared [spacing / the 2nd electrode 22 and / predetermined] it in the 4th electrode 24 further. 31, 33, and 34 are the lead wire (pre-insulation line) linked to each of the 1st electrode, the 3rd electrode, and the 4th electrode. R is the membrane resistance prepared by printing over the 2nd electrode 22 and the 4th electrode 24. It is the piece of a low-melt point point fusible alloy which connected A between the point of the 1st electrode 21, and the 2nd electrode 22, and the piece of a low-melt point fusible alloy which connected B between the points of the 2nd electrode 22 and the 3rd electrode 23, and when the pieces A and B of a low-melt point point fusible alloy are the same quality of the material and the same configuration, as shown in drawing, you may make it a successive line. 4 is the flux applied on the pieces A and B of a low-melt point point fusible alloy. 5 has used the insulating material which can be covered with ordinary temperature, for example, a roomtemperature-setting epoxy resin, so that it may be the insulating layer which prepared it as covered one side of an insulating substrate 1 and a melting flow of the above-mentioned piece of a low-melt point fusible alloy or the flux may not be carried out.

[0010] It is used in order, as for the protection component concerning this invention, to intercept the device from a power source, if an overvoltage acts on a protected device, and <u>drawing 2</u> is a circuit diagram for explaining the busy condition, and, as for F, the overvoltage sensing energization circuit is shown for the protection component which E requires for this invention, respectively. In <u>drawing 2</u>, the protection component



E and the overvoltage sensing energization circuit F which start this invention between the protected device Z and a power source S are incorporated. The collector of Transistor Tr is connected to the 4th electrode 24 of the protection component E. The high-voltage lateral electrode of zener diode D and the 3rd electrode 23 of the protection component E are connected to the high-voltage side edge child of the protected device Z, the 1st electrode 21 of the protection component E is connected to the high-voltage side edge child of a power source S, and the emitter of Transistor Tr is grounded. In the circuit shown in drawing 2, if the overvoltage more than the breakdown voltage of zener diode D acts on Device Z Base current flows to Transistor Tr, the collector current which becomes size in connection with this flows, and membrane resistance R generates heat. It is melted this generating heat being transmitted to the pieces A and B of a low-melt point point fusible alloy through the 2nd electrode 22, and the pieces A and B of both the low-melt point fusible alloy receiving an activity operation of existing fused flux, and while the protected device Z is intercepted from a power source S, membrane resistance R is intercepted from a power source S. Therefore, after the piece B of a low-melt point point fusible alloy is melted, even if the overvoltage condition of Device Z is maintained for residual charge and Transistor Tr is in switch-on, exoergic continuation of membrane resistance R can be eliminated for the cutoff from the power source S of the membrane resistance R by fusing of the piece A of a low-melt point point fusible alloy. In the above, the high-voltage lateral electrode of zener diode D may be connected to the 1st electrode 21 side.

[0011] In the above, it contributes effectively to fusing of a melting low-melt point point metal that an insulating substrate crawls molten metal and that an electrode is well damp in molten metal, and the surface smooth nature of an insulating substrate is also important conditions (element which make it easy to flow molten metal). The ceramic plate is excellent in surface smooth nature compared with the screen-stencil film of glass, and advantageous for ****. In the protection component concerning this invention, as shown in drawing 3, use the piece B of a low-melt point point fusible alloy as a fuse to the circuit part Zb, use the piece A of a low-melt point point fusible alloy as a fuse to the circuit part Za, and it sets to drawing 3. Breakdown voltage Vb of zener diode Db is made lower than the breakdown voltage Va of zener diode Da. The melting point of the piece B of a low-melt point point fusible alloy is made lower than the melting point of the piece A of a low-melt point point fusible alloy. It is made to flow through zener diode Db in the overvoltage of Vb-Va. Base current A sink, If carry out energization generation of heat of the resistance R of the protection component E by the collector current corresponding to this **-SU current, the piece B of a low-melt point point fusible alloy is made to melt, the circuit part Zb is intercepted from a power source (second-s' is a power supply terminal) and the overvoltage more than Va acts after that It is made to flow through NADAIO-DO Da, energization generation of heat of the resistance R of the protection component E can be carried out by the collector current corresponding to a sink and this **-SU current for base current, the piece A of a low-melt point point fusible alloy can be made to be able to melt, and the circuit part Za can also be made to intercept from a power source (for second-s' to be a power supply terminal).

[0012] In the protection component concerning this invention, a ceramic plate with a thickness of 100-1200 micrometers, for example, 96% alumina-ceramics plate, can be used for an insulating substrate. In addition, a metal is used as a parent, and use is also possible although insulating processing was carried out. Usually (3mm - 20mm) let the flat-surface dimension of an insulating substrate be the square or rectangle of x (3mm - 20mm). the protection component concerning this invention -- it is and the low-melting-alloys wire whose liquidus-line temperature is 75 degrees C - 300 degree-C diameter of 100 micrometers - 1200 micrometers, the low-melting alloy square wire of the same cross section as this, or a low-melting-alloys foil can be used for the piece of a low-melt point point fusible alloy. the protection component concerning this invention -- it is, and an electrode screen-stencils conductive paste (conductor being the mixture of powder and a cover coat a conductor powder a silver-platinum system, a silver-palladium system, a copper system), and can form it by the ability burning this. Moreover, an insulating substrate with an electrode can also be obtained by etching of the copper foil of a copper foil laminated circuit board. the protection component concerning this invention -- it is, membrane resistance screen-stencils the mixture of resistive paste, for example, ruthenium oxide powder, or carbon powder, and a cover coat on an insulating substrate, it can form by the ability burning this, and thickness is usually set to 1-30 micrometers. The membrane resistance of a Ti-Si system can also be used for membrane resistance. Trimming can also be performed, after forming a glass protective coat on membrane resistance so that a crack may not occur in membrane resistance in this case although trimming performed when you needed





resistance adjustment of membrane resistance. Furthermore, for long term stability etc., when protection is required, a protective coat, for example, glass membrane, is formed on membrane resistance. The lap condition of a membrane resistance edge and an electrode edge is good also considering any as the bottom. It replaces with such membrane resistance and use of a chip resistor is also possible.

[0013] In the protection component concerning this invention, flux prevents oxidation of the piece of a low-melt point point fusible alloy, and it is used in order to dissolve some oxide films of the piece of a low-melt point point fusible alloy and to make fragmentation of a melting alloy easy, it usually uses rosin as a principal component, and can use what added the activator (for example, hydrochloride of diethylamine) if needed. [0014] In order to manufacture the protection component concerning this invention, the 1st electrode - the 4th electrode are formed in one side of an insulating substrate. Membrane resistance is printed, a glass protective coat is formed on membrane resistance, and trimming adjusts resistance if needed. When resistance protection is required Glass membrane is formed on membrane resistance, the pieces A and B of a low-melt point fusible alloy are connected, lead wire is connected to an electrode, flux is applied to the piece of a low-melt point point fusible alloy, subsequently to the epoxy resin liquid of ordinary temperature a substrate is immersed, and the approach of carrying out desiccation hardening of the dipcoat layer can be used. [0015]

[Effect of the Invention] In the protection component concerning this invention, it has the resistor of a piece, and two pieces of a low-melt point point fusible alloy. When an overvoltage acts on a protected device, while making both pieces of a low-melt point point fusible alloy melt by energization generation of heat of a resistor and intercepting a protected device from a power source, a resistor can be intercepted from a power source. Compared with the configuration which prepares a resistor to each of the conventional example, i.e., the piece of both the low-melt point point fusible alloy, melts one piece of a low-melt point point fusible alloy by energization generation of heat of one resistor, and melts the piece of a low-melt point point fusible alloy of another side by energization generation of heat of the resistor of another side, it is structurally simple. [0016] Moreover, prepare insulating glass membrane on membrane resistance, and it differs from the conventional example which has allotted the piece of a low-melt point point fusible alloy in piles on this insulating glass membrane. It allots without piling up membrane resistance and the piece of a low-melt point point fusible alloy, and is the front face (on screen-stencil) of the above-mentioned insulating glass membrane. Since the irregularity resulting from a screen mesh was avoided, and twisted and the twist has also allotted the piece of a low-melt point point fusible alloy on the ceramic insulating substrate on the front face of smooth, a melting alloy is made to flow smoothly, it makes divide quickly and obtains, and the outstanding actuation nature can be guaranteed. Furthermore, when you need resistance adjustment, since what is necessary is just to perform resistance adjustment by trimming about the membrane resistance of a piece, a manufacture man day can be reduced and it is advantageous on manufacture. Furthermore, a different circuit part can also be intercepted from a power source to a different overvoltage again.

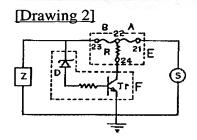
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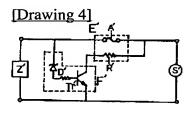
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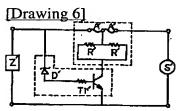
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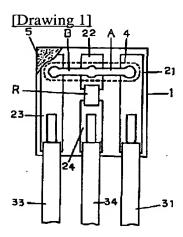
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DRAWINGS

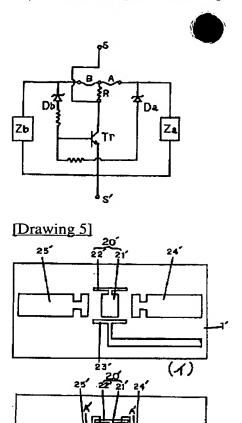


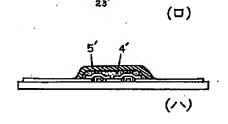






[Drawing 3]





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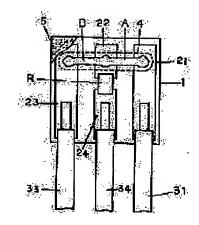
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SOLUTION: The first electrode 21, the second electrode 22, the third electrode 23 and the fourth electrode 24 are arranged on one side of an insulating board 1. In addition, a resistor R is provided across the second electrode 22 and the fourth electrode 24. Also, low-fusion point fusible alloy pieces A and B are respectively laid between the first electrode 21 and the second electrode 22, and between the second electrode 22 and the third electrode 23. Furthermore, flux 4 is applied to the low-fusion point fusible alloy pieces A and B, and one side of the insulating board 1 is covered with an insulation layer 5.



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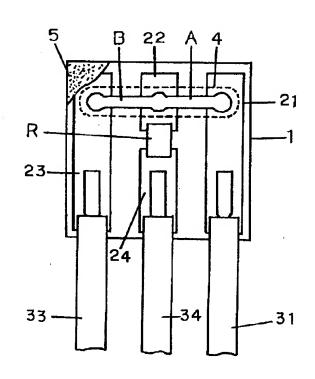
(21)出願番号 特顧平8-289139 (71)出願人 000225337 内橋エステック株式会社 大阪府大阪市中央区島之内1丁目11番28号 (72)発明者 植村 充明 大阪市中央区島之内1丁目11番28号 内橋 エステック株式会社内 (74)代理人 弁理士 松月 美勝

(54) 【発明の名称】 保護素子及びその使用方法

(57)【要約】

【課題】機器の過電圧を検知し膜抵抗を通電発熱させて 低融点可溶合金片を溶断させ、機器及び膜抵抗を電源よ り遮断する保護索子を対象とし、構造が簡単で製造が容 易な作動性に優れた保護索子及びその保護索子の使用方 法を提供する。

【解決手段】絶縁基板1の片面上に第1電極21、第2電極22、第3電極23及び第4電極24を設け、第2電極22と第4電極24とにわたって抵抗Rを設け、第1電極21と第2電極22との間及び第2電極22と第3電極23との間に低融点可溶合金片A及びBをそれぞれ接続し、低融点可溶合金片にフラックス4を塗布し、上記絶縁基板の片面を覆って絶縁層5を被覆して成る。



【特許請求の範囲】

【請求項1】絶縁基板の片面上に第1電極、第2電極、第3電極及び第4電極を設け、第2電極と第4電極とにわたって抵抗を設け、第1電極と第2電極との間及び第2電極と第3電極との間に低融点可溶合金片A及びBをそれぞれ接続し、低融点可溶合金片にフラックスを塗布し、上記絶縁基板の片面を覆って絶縁層を被覆して成ることを特徴とする保護素子。

【請求項2】請求項1乃至3何れか記載の保護素子の第1電極を電源側に、第3電極を被保護機器側にそれぞれ接続し、第1電極または第3電極と第4電極との間に被保護機器の過電圧を検知し、上記抵抗を通電発熱させる過電圧検知通電回路を接続することを特徴とする保護素子の使用方法。

【請求項3】請求項1記載の保護索子の低融点可溶合金 片Aの融点と低融点可溶合金片Bの融点とを異にし、各 低融点可溶合金片を異なる回路部分に対するヒューズと して用い、異なる過電圧を検出して保護索子の抵抗を異 なる温度で通電発熱させる過電圧検知通電回路を接続 し、小なる過電圧で抵抗を通電発熱させて一方の低融点 可溶合金片の溶断で一方の回路部分を電源から遮断し、 その後の大なる過電圧で抵抗を通電発熱させて他方の低 融点可溶合金片の溶断で他方の回路部分を電源から遮断 することを特徴とする保護索子の使用方法。

【発明の詳細な説明】

[0001]

【発明の属する技術分野】本発明は過電圧から電気機器 を保護するために用いる保護素子及びその使用方法に関 するものである。

[0002]

【従来の技術】機器に過電圧が作用したときに機器を電源から遮断する場合、膜抵抗と低融点可溶合金片とを絶縁基板の片面上に並設し、絶縁基板の片面を絶縁層で被覆して成る保護索子を使用し、図4に示すように、この保護索子E'及び過電圧検知通電回路F'、例えば、トランジスタTr'のベース側にツエナダイオードD'を接続して成る回路F'を電源S'と被保護機器Z'との間に挿入し、機器Z'にツエナダイオードD'の降伏田は上の逆電圧が作用すると、ベース電流が流れ、このベース電流に応じコレクタ電流が流れて膜抵抗R'が発熱し、低融点可溶合金片A'が溶断されることで機器Z'を電源S'から遮断することが公知である。

【0003】しかしながら、上記の保護素子では、低融点可溶合金片A'の溶断で機器Z'が電源から遮断されても、機器Z'がキャパシティブな負荷の場合、例えば蓄電池の場合、残留電圧のためにベース電流が流れ続けて膜抵抗R'の通電発熱が継続されることがあり、危険である。

【0004】そこで、図5の(イ)に示すように、中央 ヒューズ電極21′とヒーター片側T字形電極22′と を結合した複合電極20'、ヒーター他側T字形電極2 3' 及びヒーズ両側電極 2 4'、 2 5'とを基板 1'に 印刷形成し、図5の(ロ)に示すように、ヒーター片側 T字形電極22'とヒーター他側T字形電極23'との T字形両アーム間にわたってそれぞれ膜抵抗R'、R' を設け、各膜抵抗上に絶縁層 i'、 i'を設け、複合電 極20'の中央ヒューズ電極21'とヒューズ両側電極 24' ね25' との間にそれぞれ低融点可溶合金片 A'、A'を接続し、更に図5の(ハ)に示すように、 フラックス層 4′及び外部絶縁層 5′を被覆して成る保 護索子を用いることが提案されている(特開平7-15 3367号)。この保護索子を組み込んだ保護回路で は、図6に示す通り膜抵抗R'-低融点可溶合金片A' の対を2組備え、各対の膜抵抗R'の通電発熱でその対 の低融点可溶合金片A'を溶断している。而して、機器 Z' 側にツエナダイオードD' の降伏電圧以上の逆電圧 が作用すると、トランジスタTr'にベース電流が流 れ、コレクタ電流が流れて両膜抵抗 R'、R'が通電発 熟され、各膜抵抗R'、R'の通電発熱で各低融点可溶 合金片A'、A'が溶断されて機器Z'が電源S'から 遮断されると共に膜抵抗R'、R'が電源S'から遮断 される。

[0005]

【発明が解決しようとする課題】しかしながら、上記の保護素子では膜抵抗一低融点可溶合金片の対が二組であるために2個の膜抵抗についての抵抗値調整が必要であって製造がやっかいであり、また、膜抵抗一低融点可溶合金片を平面的に2組設ける必要があるため保護素子の小サイズ化にも不利である。更に、膜抵抗上の絶縁層、例えばガラス膜はスクリーン印刷により形成され、スクリーンのメッシュに起因しての凹凸化か避け難く、かかるもとでは、その上での低融点可溶合金片の円滑な球状化分断を保証し難い。

【 0 0 0 6 】本発明の目的は、機器の過電圧を検知し膜 抵抗を通電発熱させて低融点可溶合金片を溶断させ、機 器及び膜抵抗を電源より遮断する保護素子を対象とし、 構造が簡単で製造が容易な作動性に優れた保護素子及び その保護素子の使用方法を提供することにある。

[0007]

【課題を解決しようとする手段】本発明に係る保護素子は、絶縁基板の片面上に第1電極、第2電極、第3電極及び第4電極を設け、第2電極と第4電極とにわたって抵抗を設け、第1電極と第2電極との間及び第2電極と第3電極との間に低融点可溶合金片A及びBをそれぞれ接続し、低融点可溶合金片にフラックスを塗布し、上記絶縁基板の片面を覆って絶縁層を被覆して成る構成である。本発明に係る保護素子は、第1電極を電源側に、第3電極を被保護機器側にそれぞれ接続し、第1電極または第3電極と第4電極との間に被保護機器の過電圧を検知し、上記抵抗を通電発熱させる過電圧検知通電回路を

接続して使用できる。

【0008】また、本発明に係る保護素子は、低融点可溶合金片Aの融点と低融点可溶合金片Bの融点とを異にし、各低融点可溶合金片を異なる回路部分に対するヒューズとして用い、異なる過電圧を検出して保護素子の抵抗を異なる温度で通電発熱させる過電圧検知通電回路を接続し、小なる過電圧で抵抗を通電発熱させて一方の低融点可溶合金片の溶断で一方の回路部分を電源から遮断し、その後の大なる過電圧で抵抗を通電発熱させて他方の低融点可溶合金片の溶断で他方の回路部分を電源から遮断することによっても使用できる。

[0009]

【発明の実施の形態】以下、図面を参照しつつ本発明の 実施の形態について説明する。図1は本発明に係る保護 **素子の一例を示している。図1において、1は耐熱性の** 絶縁基板、例えばセラミックス板である。21~24は 絶縁基板の片面上に印刷形成した膜状の第1電極~第4 電極であり、第1電極21の先端部と第3電極23の先 端部との間に第2電極22を設け、更に第4電極24を 第2電極22と所定の間隔を隔てて設けてある。31、 33及び34は第1電極、第3電極及び第4電極のそれ ぞれに接続したリード線(絶縁被覆線)である。Rは第 2電極22と第4電極24とにわたって印刷により設け た膜抵抗である。Aは第1電極21の先端部と第2電極 22との間に接続した低融点可溶合金片、Bは第2電極 22と第3電極23の先端部との間に接続した低融点可 溶合金片であり、低融点可溶合金片A、Bが同一材質、 同一形状の場合、図のように連続線にしてもよい。4は 低融点可溶合金片A及びB上に塗布したフラックスであ る。5は絶縁基板1の片面を覆うようにして設けた絶縁 層であり、上記低融点可溶合金片やフラックスを溶融流 動させることのないように、常温で被覆できる絶縁材、 例えば常温硬化エポキシ樹脂を使用してある。

【〇〇1〇】本発明に係る保護索子は、被保護機器に過 電圧が作用すると、その機器を電源から遮断するために 使用され、図2はその使用状態を説明するための回路図 であり、Eは本発明に係る保護素子を、Fは過電圧検知 通電回路をそれぞれ示している。図2において、被保護 機器スと電源Sとの間に本発明に係る保護索子Eと過電 圧検知通電回路Fとを組み込み、トランジスタTrのコ レクタを保護索子Eの第4電極24に接続し、ツエナダ イオードDの高電圧側電極及び保護索子Eの第3電極2 3を被保護機器との高電圧側端子に接続し、保護素子E の第1電極21を電源Sの高電圧側端子に接続し、トラ ンジスタTrのエミッタを接地してある。図2に示す回 路において、機器とにツエナダイオードDの降伏電圧以 上の過電圧が作用すると、トランジスタTェにベース電 流が流れ、これに伴い大なるコレクタ電流が流れて膜抵 抗尺が発熱され、この発生熱が第2電極22を介し低融 点可溶合金片A及びBに伝達されて両低融点可溶合金片 A及びBが既溶融フラックスの活性作用を受けつつ溶断され、被保護機器 Z が電源 S から遮断されると共に膜抵抗 R が電源 S から遮断される。従って、低融点可溶合金 片Bが溶断されたのち、機器 Z の過電圧状態が残留電荷のために維持されてトランジスタ T r が導通状態にあっても、低融点可溶合金片 A の溶断による膜抵抗 R の電源 S からの遮断のために、膜抵抗 R の発熱続行を排除できる。上記において、ツエナダイオード D の高電圧側電極を第1電極 21 側に接続してもよい。

【0011】上記において、溶融低融点金属の溶断に は、絶縁基板が溶融金属をはじくことと、電極が溶融金 属によく濡れることが有効に寄与し、絶縁基板の表面平 滑性も重要な条件である(溶融金属を流れ易くする要 **索)。而るに、セラミックス板は、ガラスのスクリーン** 印刷膜に較べ表面平滑性に優れており有利である。本発 明に係る保護索子においては、図3に示すように、低融 点可溶合金片Bを回路部分Zbに対するヒューズとして 用い、低融点可溶合金片Aを回路部分Zaに対するヒュ ーズとして用い、図3において、ツエナダイオードDb の降伏電圧VbをツエナダイオードDaの降伏電圧Va よりも低くし、低融点可溶合金片日の融点を低融点可溶 合金片Aの融点よりも低くし、Vb~Vaの過電圧でツ エナダイオードDbを導通させてベース電流を流し、こ のペース電流に対応するコレクタ電流で保護索子Eの抵 抗Rを通電発熱させ低融点可溶合金片Bを溶断させて回 路部分Zbを電源(sーs'は電源端子)から遮断し、 その後、Va以上の過電圧が作用すると、ナダイオード Daを導通させてベース電流を流し、このベース電流に 対応するコレクタ電流で保護素子Eの抵抗Rを通電発熱 させ低融点可溶合金片Aを溶断させて回路部分Zaを電 源(s-s'は電源端子)から遮断させることもでき る。

【0012】本発明に係る保護索子において、絶縁基板 には厚み100~1200μmのセラミックス板、例え ば、96%アルミナセラミックス板を使用できる。その 他、金属を母体とし、絶縁処理したものの使用も可能で ある。絶縁基板の平面寸法は、通常(3mm~20m m)×(3mm~20mm)の正方形乃至は長方形とさ れる。本発明に係る保護素子おいて、低融点可溶合金片 には液相線温度が75℃~300℃直径100μm~1 200μmの低融点合金丸線、これと同一断面積の低融 点合金角線または低融点合金箔を使用できる。本発明に 係る保護索子おいて、電極は導体ペースト(導体粉末と 釉薬との混合物であり、導体粉末には銀ー白金系、銀ー パラジウム系、銅系)をスクリーン印刷し、これを焼き 付けることにより形成できる。また、銅箔積層基板の銅 箔のエッチングにより電極付き絶縁基板を得ることもで きる。本発明に係る保護索子おいて、膜抵抗は抵抗ペー スト、例えば、酸化ルテニウム粉末または炭素粉末と釉 薬との混合物を絶縁基板上にスクリーン印刷し、これを

焼き付けることにより形成でき、膜厚は通常 1 ~ 3 0 μ mとされる。膜抵抗には T i - S i 系の膜抵抗を使用することもできる。膜抵抗の抵抗値調整を必要とする場合、トリミングにより行うが、この際膜抵抗に亀裂が発生することのないように、膜抵抗上にガラス保護膜を形成したうえで、トリミングを行うこともできる。更に、長期安定性等のために保護が必要な場合は、膜抵抗場に保護膜、例えば、ガラス膜を形成する。膜抵抗端部と電極端部との重なり状態は、何れを下側としてもよい。これらの膜抵抗に代え、チップ抵抗の使用も可能である。

【0013】本発明に係る保護索子において、フラックスは低融点可溶合金片の酸化を防止し、かつ低融点可溶合金片の多少の酸化膜を溶解して溶融合金の分断を容易にするために用いられ、通常ロジンを主成分とし、必要に応じて活性剤(例えば、ジエチルアミンの塩酸塩)を添加したものを使用できる。

【0014】本発明に係る保護索子を製造するには、絶縁基板の片面に第1電極〜第4電極を形成し、膜抵抗を印刷し、膜抵抗上にガラス保護膜を形成し、必要に応じトリミングにより抵抗値を調整し、抵抗保護が必要な場合は、膜抵抗上にガラス膜を形成し、低融点可溶合金片 A及びBを接続し、電極にリード線を接続し、低融点可溶合金片にフラックスを塗布し、次いで基板を常温のエポキシ樹脂液に浸漬し、その浸漬被覆層を乾燥硬化させる方法を使用できる。

[0015]

【発明の効果】本発明に係る保護素子においては、一個の抵抗体と二個の低融点可溶合金片を有し、被保護機器に過電圧が作用したときに抵抗体の通電発熱により両方の低融点可溶合金片を溶断させて被保護機器を電源から遮断すると共に抵抗体を電源から遮断することができ、従来例、すなわち、両低融点可溶合金片のそれぞれに対し抵抗体を設け、一方の抵抗体の通電発熱で一方の低融点可溶合金片を溶断し、他方の抵抗体の通電発熱で他方の低融点可溶合金片を溶断する構成に較べ、構造的に簡易である。

【0016】また、膜抵抗上に絶縁ガラス膜を設け、この絶縁ガラス膜上に低融点可溶合金片を重ねて配してい

る従来例とは異なり、膜抵抗と低融点可溶合金片とを重ねずに配し、上記絶縁ガラス膜の表面(スクリーン印刷上、スクリーンメッシュに起因する凹凸が避けられない)よりも平滑表面のセラミックス絶縁基板上に低融点可溶合金片を配しているから、溶融合金をスムーズに流動させて迅速に分断させ得、優れた作動性を保証できる。更に、抵抗値調整を必要とする場合、トリミングによる抵抗値調整を一個の膜抵抗について行えばよいから、製造工数を低減でき、製造上有利である。更にまた、異なる回路部分を異なる過電圧に対し電源から遮断することもできる。

【図面の簡単な説明】

【図1】本発明に係る保護素子の一例を示す説明図である。

【図2】本発明に係る保護素子を用いた回路の一例を示す説明図である。

【図3】本発明に係る保護素子を用いた回路の一例を示す説明図である。

【図4】従来の保護回路を示す説明図である。

【図5】従来の保護素子を示す説明図である。

【図6】図5の保護索子を用いた保護回路を示す説明図 である。

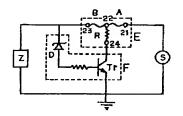
【符号の説明】

1

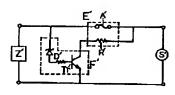
•	ACASS CELIX
2 1	第1電極
2 2	第2電極
2 3	第3電極
2 4	第4電極
Α	低融点可溶合金片
В	低融点可溶合金片
R	抵抗
4	フラックス
5	絶縁層
E	保護素子
F	過電圧検知通電回路
Z	被保護機器
S	電源

絶縁基板

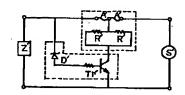


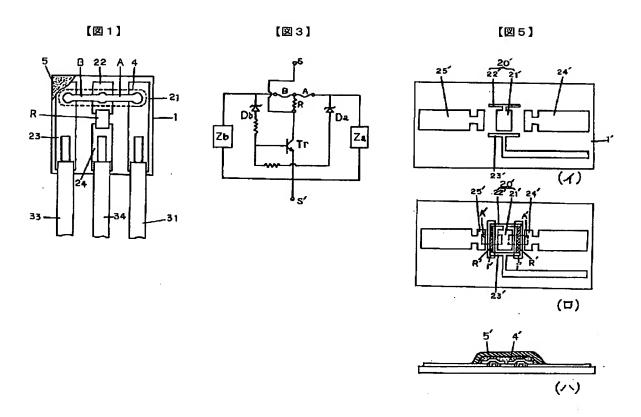


【図4】



【図6】





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